

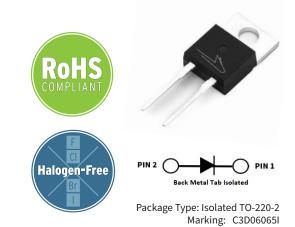
# C3D06065 3rd Generation 650 V, 6 A Silicon Carbide Schottky Diode

#### Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.

#### **Features**

- Low Forward Voltage (V $_{\rm F}$ ) Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior
- Electrically Isolated Package (2.5kV)



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#### **Applications**

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters
- AC/DC Converters

## **Maximum Ratings** ( $T_c = 25^{\circ}C$ Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	650				
DC Blocking Voltage	V <sub>DC</sub>	650	V			
Continuous Forward Current		13	A	T <sub>c</sub> = 25 °C	Fig. 3	
	I <sub>F</sub>	6		T <sub>c</sub> = 135 °C		
Repetitive Peak Forward Surge Current	I <sub>FRM</sub>	24		$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ Half Sine Wave}$		
		16		$T_c = 110 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$		
Non-Repetitive Forward Surge Current	I <sub>FSM</sub>	63		$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ Half Sine Wave}$	Fig. 8	
		49		T <sub>c</sub> = 110 °C,t <sub>p</sub> = 10 ms, Half Sine Wave		
Non-Repetitive Peak Forward Surge Current	l <sub>F,Max</sub>	540		$T_{c} = 25 \text{ °C}, t_{p} = 10 \ \mu s, Pulse$		
		460		$T_{c} = 110^{\circ}C, t_{p} = 10 \ \mu s, Pulse$		
Power Dissipation	P <sub>tot</sub>	45.5	w	T <sub>c</sub> = 25 °C	Fig. 4	
		19.5		T <sub>c</sub> = 110 °C		

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# **Electrical Characteristics**

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes
E IVI		1.5	1.7		I <sub>F</sub> = 6 A, T <sub>j</sub> = 25 °C	F' 1
Forward Voltage	V <sub>F</sub>	2.0	2.4	V	I <sub>F</sub> = 6 A, T <sub>j</sub> = 175 °C	Fig. 1
Reverse Current		8	40	μA	V <sub>R</sub> = 650 V, T <sub>j</sub> = 25 °C	Fig. 2
	R	15.5	160		V <sub>R</sub> = 650 V, T <sub>j</sub> = 175 °C	
Total Capacitive Charge	Q <sub>c</sub>	15		nC	$V_{R} = 400 \text{ V}, \text{ T}_{j} = 25 \text{ °C}, \text{ I}_{F} = 6 \text{ A}$	Fig. 5
		295			$V_{R} = 0 V, T_{j} = 25 °C, f = 1 MHz$	
Total Capacitance	с	28.5		pF	$V_{R} = 200 \text{ V}, \text{ T}_{j} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$	Fig. 6
		25.5			$V_{R} = 400 \text{ V}, \text{ T}_{j} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$	
Capacitance Stored Energy	E <sub>c</sub>	2.3		μJ	V <sub>R</sub> = 400 V	Fig. 7

Notes:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

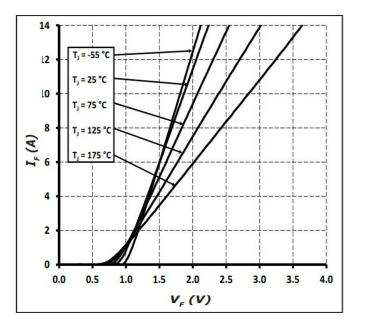
## **Thermal & Mechanical Characteristics**

Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	R <sub>0, JC (TYP)</sub>	3.3	°C / W	
Junction Temperature	T <sub>j</sub>	-55 to +175		
Case & Storage Temperature	T <sub>c</sub>	-55 to +175	- °C	
TO 200 Manualia - Tanana		1	Nm	M3 Screw
TO-220 Mounting Torque		8.8	lbf-in	6-32 Screw

# **Electrostatic Discharge (ESD) Classifications**

Parameter	Symbol	Notes
Human Body Model	НВМ	Class 3B (≥ 8000 V)
Charge Device Model	CDM	Class C3 (≥ 1000 V)

## **Typical Performance**



**Figure 1** Forward Characteristics

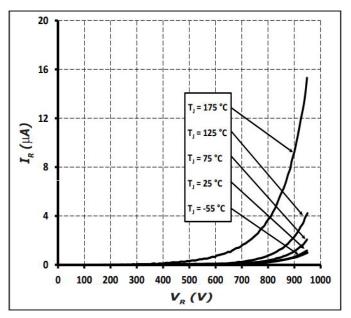
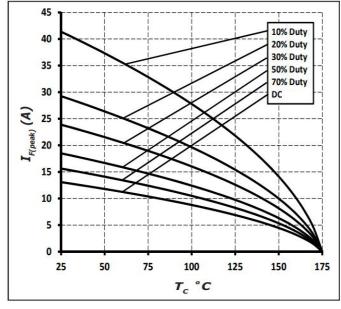
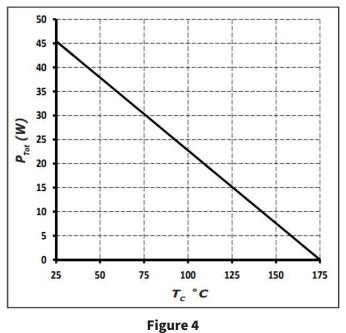


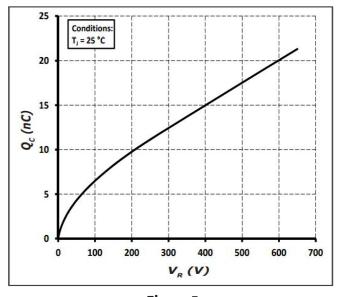
Figure 2 Reverse Characteristics



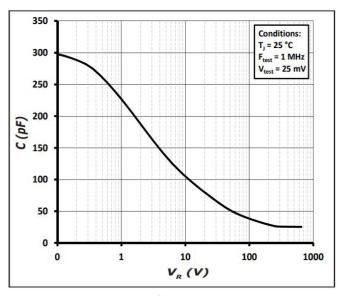
**Figure 3** Current Derating



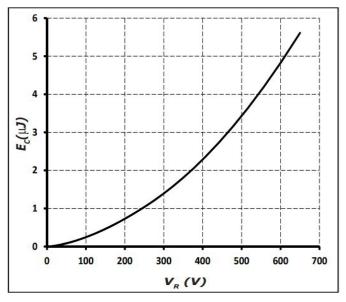
Power Derating



**Figure 5** Total Capacitance vs. Reverse Voltage



**Figure 6** Capacitace vs. Reverse Voltage



**Figure 7** Capacitance Stored Energy

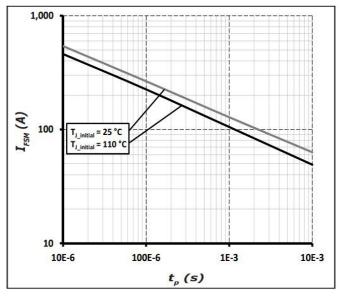
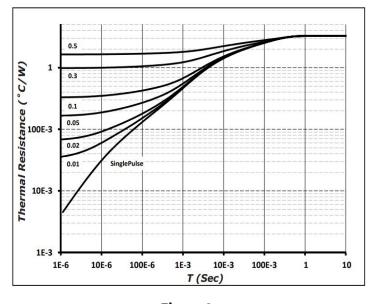
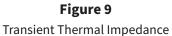


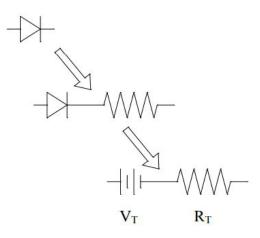
Figure 8

Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)





#### **Diode Model**



$$\begin{split} Vf_T &= V_T + \text{ If } * R_T \\ V_T &= 0.96 + (T_J * -1.1*10^{-3}) \\ R_T &= 0.07 + (T_J * 7.4*10^{-4}) \end{split}$$

Note:  $T_j$  = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

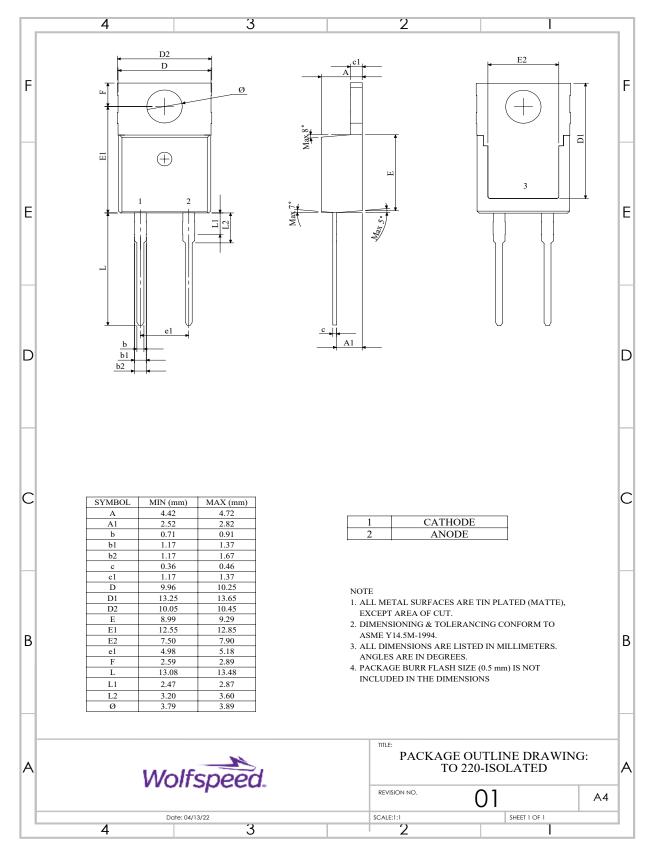
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## **Package Dimensions & Pin-Out**

Package: TO-220-2



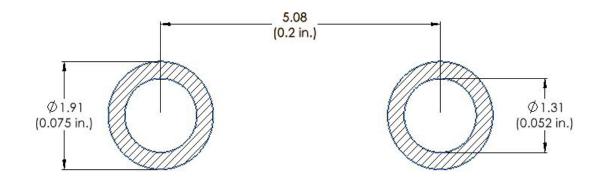
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## **Recommended Solder Pad Layout**

Primary dimensions shown in mm.



# **Product Ordering Information**

Order Number	Packing Type
C3D06065I	Tube

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# **Revision History**

Document Version	Date of Release	Description of Changes
В	January-2016	Initial Release
4	May-2023	Update Package Drawing Update Landing Pad



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#### **Contact info:**

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